Transimpedance Amplifier

Description

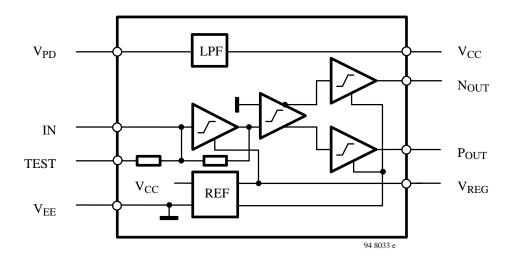
U6791B-C is a low-noise, wideband IC designed for amplifying low-level current signals delivered by PIN photo diodes in fiberoptic receiver systems. It contains a transimpedance amplifier and a voltage regulator that provides a supply independent voltage with a positive temperature coefficient to hold bandwidth constant over temperature. For best performance, an additional pin, V_{PD} , is used to filter the supply voltage for the photo diode. The circuit provides quasi-complementary outputs and works best ac coupled to U6792B-D.

Features

- 220 MHz bandwidth over temperature and supply voltage range
- Wide 60 dB input dynamic range
- Low-power design: 20 mA maximum

- Low-noise design
- Temperature compensated
- Available in SO-8 package or chip form
- Transimpedance of 14 kΩ typical

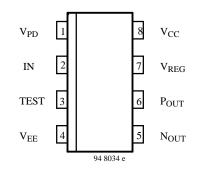
Block Diagram



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Pin Description

Pin	Symbol	Function
1	V _{PD}	Filtered positive supply voltage
2	IN	Photo diode current input
3	TEST	Testpoint (resistance between IN and TEST)
4	V _{EE}	Negative supply voltage
5	N _{OUT}	Negative output
6	P _{OUT}	Positive output
7	V _{REG}	Decoupling the internal refer- ence voltage
8	V _{CC}	Positive supply voltage, nor- mally grounded



Absolute Maximum Ratings

Parameters		Symbol	Value	Unit
Supply voltage	apply voltage Pin 4		6.0	V
Input voltage Pin 3		Vi	V _{EE} to GND	V
Input current Pin 2		Ii	200	μΑ
Junction temperature		T _i	125	°C
Storage temperature range		T _{stg}	-40 to +125	°C

Operating Range

Paramete	Symbol	Value	Unit	
Supply voltage range Pin 8		V _{EE}	4.5 to 5.7	V
Ambient temperature range		T _{amb}	-40 to +85	°C

Thermal Resistance

Parameters		Symbol	Value	Unit
Junction ambient	SO-8	R _{thJA}	typ. 180	K/W

Electrical Characteristics

Operating conditions: $T_{amb} = 0^{\circ}C$ to 70°C, $V_{EE} = -5.2V \pm 10\%$

Parameters	Test Conditions / Pins	Symbol	Min.	Тур.	Max.	Unit
V _{EE} supply current		I _{EE}	-20	-16	-13	mA
Reference voltage *		V _{REG}	3.8	3.82	3.86	V
Test resistor between IN and TEST		R _{TEST}	60	75	90	kΩ

* measured with respect to V_{EE}

AC Electrical Characteristics

Operating conditions: $T_{amb} = 0^{\circ}C$ to 70°C, $V_{EE} = -5.2V \pm 10\%$

Parameters	Test Conditions / Pins	Symbol	Min.	Тур.	Max.	Unit
Bandwidth		BW	220			MHz
Input current range		I _{IN}	0.1		70	μΑ
Output voltage swing POUT, NOUT	$I_{IN} = 70 \ \mu A$	V _{OUT}			1.2	V
Transimpedance		RT		14		kΩ
Input equivalent noise		N _E		4		pA / \sqrt{Hz}

Functional Description

U6791B-C transforms an input current coming from a photo diode into a quasi-complementary output voltage. Output voltage can be calculated by

 $V_{OUT,PP}[mV] = R_T [k\Omega] * I_{IN} [\mu A]$

The photo diode is connected between V_{PD} and IN to reduce feedthrough of supply variations. V_{PD} provides V_{CC} by means of a dual pole low pass filter.

To maintain a constant bandwidth over supply voltage and temperature variations, V_{REG} is provided and should be decoupled by an external capacitor. For best results it is recommended to use the U6791B-C ac coupled to the U6792B-D data quantizer, because these two IC's are well matched for amplification and signal monitoring.

94 8038 e 510 V_{EE} O DATA DATA **1**00n ₹ U6791B–C 100n STATUS 100 DATA STATUS DAT \A 510 25K 25K 510 U6792B-E U6795B-D 100n 1μ 100n INHIBIT -0 V_{EE}

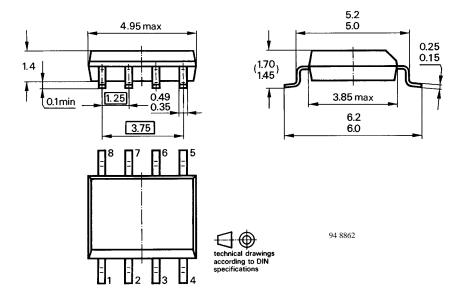
Typical Application

U6791B-C

TELEFUNKEN Semiconductors

Dimensions in mm

Package: SO 8



Ozone Depleting Substances Policy Statement

It is the policy of TEMIC TELEFUNKEN microelectronic GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

TEMIC TELEFUNKEN microelectronic GmbH semiconductor division has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

TEMIC can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice. Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use TEMIC products for any unintended or unauthorized application, the buyer shall indemnify TEMIC against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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Preliminary Information